



SamHop Microelectronics Corp.



STB31L01

Ver 1.1

N-Channel Logic Level Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
V _{DSS}	I _D	R _{DSON} (mΩ) Typ
100V	26A	49 @ V _{GS} =10V

FEATURES

- Super high dense cell design for low R_{DSON}.
- Rugged and reliable.
- TO-263 Package.



ABSOLUTE MAXIMUM RATINGS (T_C=25°C unless otherwise noted)

Symbol	Parameter	Limit	Units
V _{DS}	Drain-Source Voltage	100	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	26	A
		21.8	A
I _{DM}	-Pulsed ^a	76	A
E _{AS}	Single Pulse Avalanche Energy ^c	36	mJ
P _D	Maximum Power Dissipation	75	W
		52.5	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 175	°C

THERMAL CHARACTERISTICS

R _{θJC}	Thermal Resistance, Junction-to-Case	2	°C/W
R _{θJA}	Thermal Resistance, Junction-to-Ambient	62.5	°C/W

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ELECTRICAL CHARACTERISTICS (T_c=25°C unless otherwise noted)

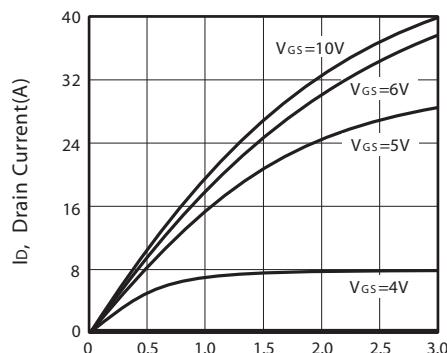
Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	100			V
I _{DS}	Zero Gate Voltage Drain Current	V _{DS} =80V , V _{GS} =0V			1	uA
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V , V _{DS} =0V			±100	nA
ON CHARACTERISTICS						
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250uA	1	2.0	3	V
R _{Ds(ON)}	Drain-Source On-State Resistance	V _{GS} =10V , I _D =13A		49	60	m ohm
g _{FS}	Forward Transconductance	V _{DS} =10V , I _D =13A		22		S
DYNAMIC CHARACTERISTICS ^b						
C _{iss}	Input Capacitance	V _{DS} =25V,V _{GS} =0V f=1.0MHz		1460		pF
C _{oss}	Output Capacitance			88		pF
C _{rss}	Reverse Transfer Capacitance			75		pF
SWITCHING CHARACTERISTICS ^b						
t _{D(ON)}	Turn-On Delay Time	V _{DD} =50V I _D =1A V _{GS} =10V R _{GEN} = 6 ohm		25		ns
t _r	Rise Time			23		ns
t _{D(OFF)}	Turn-Off Delay Time			66		ns
t _f	Fall Time			14		ns
Q _g	Total Gate Charge	V _{DS} =50V,I _D =13A,V _{GS} =10V		26		nC
Q _{gs}	Gate-Source Charge	V _{DS} =50V,I _D =13A, V _{GS} =10V		2.6		nC
Q _{gd}	Gate-Drain Charge			9.3		nC
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
V _{SD}	Diode Forward Voltage	V _{GS} =0V,I _S =4A		0.79	1.3	V

Notes

- a.Pulse Test:Pulse Width ≤ 300us, Duty Cycle ≤ 2%.
- b.Guaranteed by design, not subject to production testing.
- c.Starting T_J=25°C,L=0.5mH,V_{DD}=50V.(See Figure13)

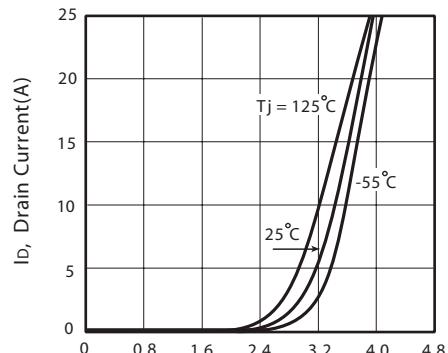
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V_{DS}, Drain-to-Source Voltage(V)

Figure 1. Output Characteristics



V_{Gs}, Gate-to-Source Voltage(V)

Figure 2. Transfer Characteristics

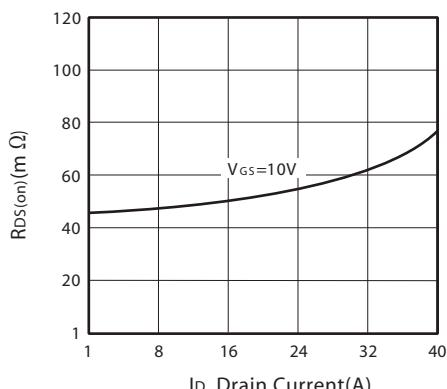


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

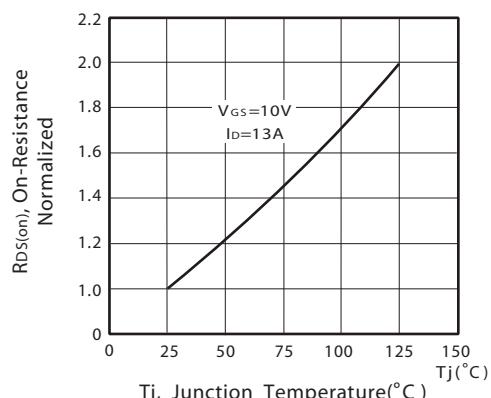


Figure 4. On-Resistance Variation with Drain Current and Temperature

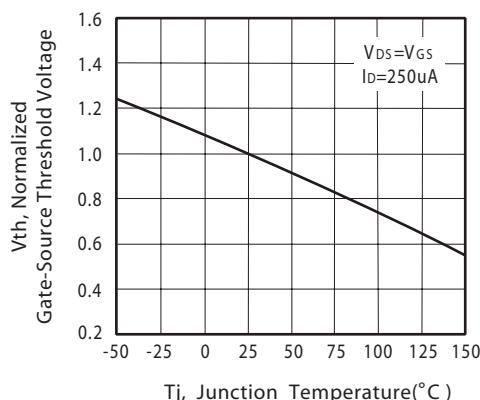


Figure 5. Gate Threshold Variation with Temperature

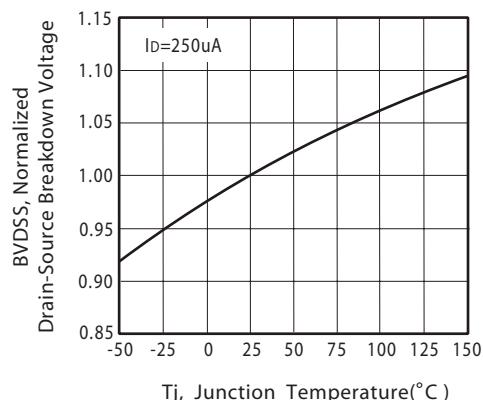
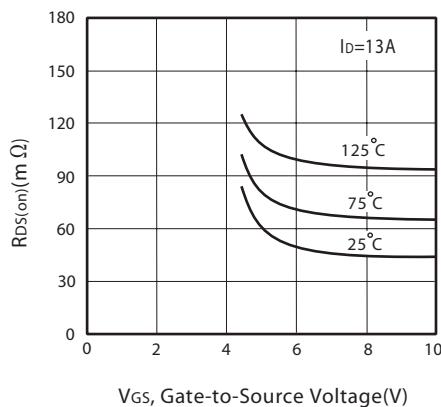


Figure 6. Breakdown Voltage Variation with Temperature

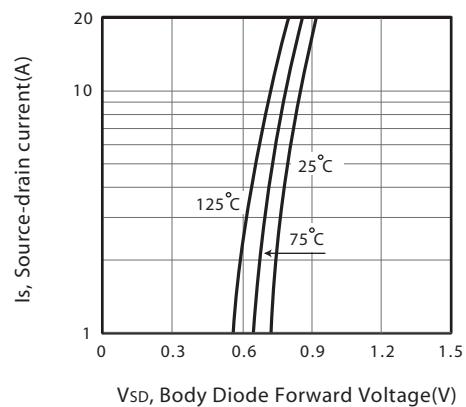
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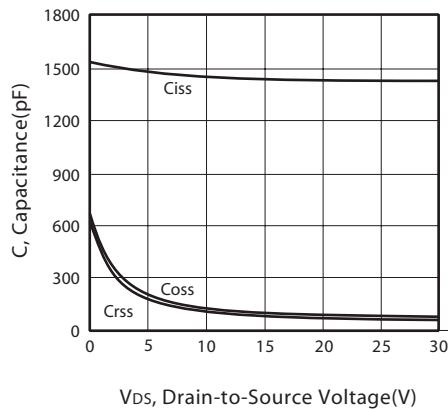
V_{GS}, Gate-to-Source Voltage(V)

Figure 7. On-Resistance vs. Gate-Source Voltage



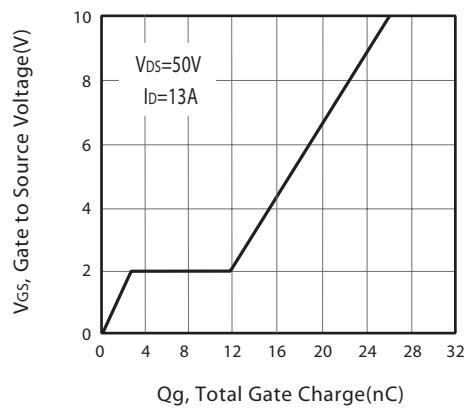
V_{SD}, Body Diode Forward Voltage(V)

Figure 8. Body Diode Forward Voltage Variation with Source Current



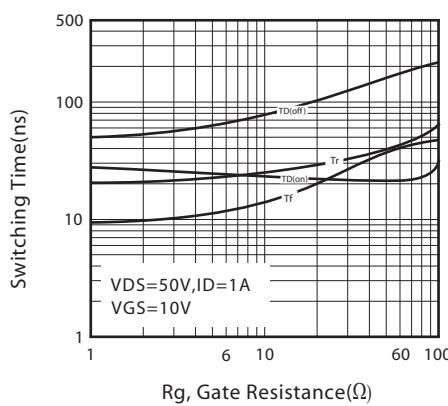
V_{DS}, Drain-to-Source Voltage(V)

Figure 9. Capacitance



Q_g, Total Gate Charge(nC)

Figure 10. Gate Charge



R_g, Gate Resistance(Ω)

Figure 11. switching characteristics

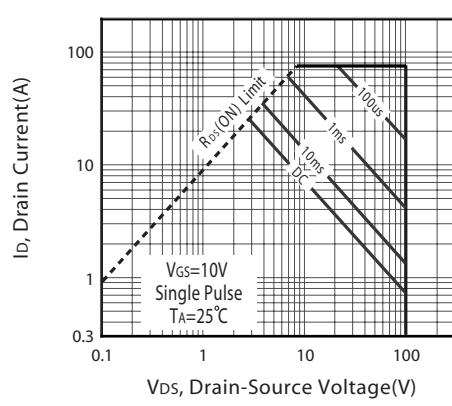
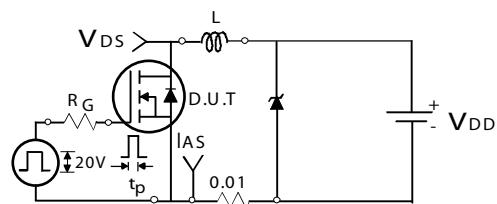


Figure 12. Maximum Safe Operating Area

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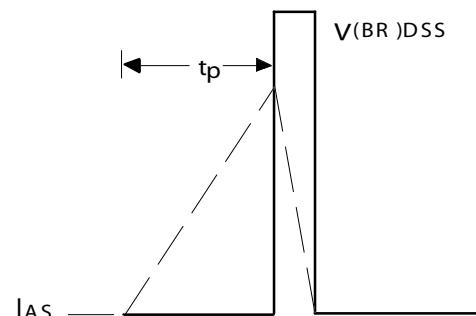
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Unclamped Inductive Test Circuit

Figure 13a.



Unclamped Inductive Waveforms

Figure 13b.

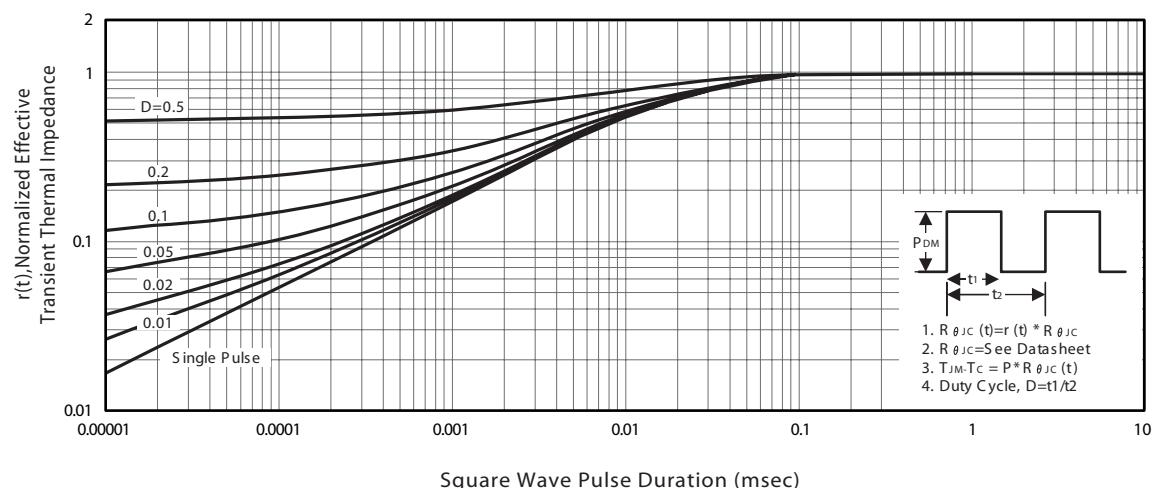
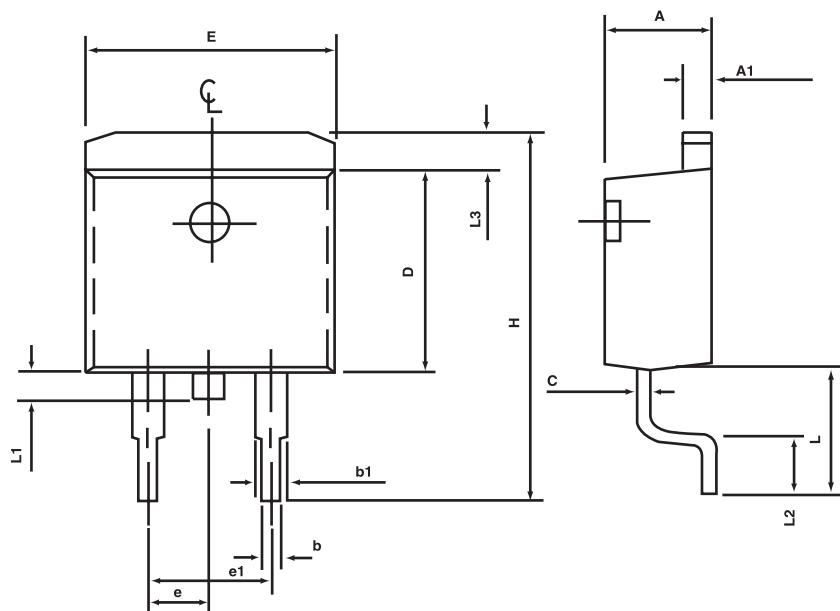


Figure 14. Normalized Thermal Transient Impedance Curve

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PACKAGE OUTLINE DIMENSIONS

TO-263AB



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.30	4.70	0.169	0.185
A1	1.22	1.32	0.048	0.055
b	0.69	0.94	0.027	0.037
b1	1.22	1.40	0.048	0.055
C	0.36	0.56	0.014	0.022
D	8.64	9.652	0.340	0.380
E	9.70	10.54	0.382	0.415
e	2.29	2.79	0.090	0.110
e1	4.83	5.33	0.190	0.210
H	14.60	15.78	0.575	0.625
L	4.70	5.84	0.185	0.230
L1	1.20	1.778	0.047	0.070
L2	2.24	2.84	0.088	0.111
L3	1.40 MAX		0.055 MAX	

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TO-263AB Tube

